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Solution-processed ZnO-chemically converted graphene gas sensor

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ABSTRACT

We report a solution-processed gas sensor based on vertically aligned ZnO nanorods (NRs) on a chemically converted graphene (CCG) film. The prepared sensor device effectively detected 2 ppm of H_2S in oxygen at room temperature. A high sensitivity of the gas sensor resulted from the growth of highly dense vertical ZnO NRs on the CCG film with numerous tiny white dots on its surface, which may provide a sufficient number of sites for the nucleation and growth of the ZnO NRs. The adsorption of oxygen on the surface of the ZnO NRs was found to be crucial for obtaining an excellent gas sensing performance of the ZnO NRs-CCG sensor.

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1. Introduction

In the past decade, one-dimensional (1-D) nanostructures such as carbon nanotubes, ZnO nanowires (NWs) or nanorods (NRs) have attracted much attention in sensor device applications [1]. Recently, two-dimensional (2-D) graphene has emerged as a high potential material and increasingly attracted attention owing to its fascinating physical properties including quantum electronic transport, extremely high mobility, high elasticity, and electromechanical modulation [2]. Future studies require a building block of multifunctional materials as well as structures, because it enables us to exploit versatile and tailor-made properties with performances far beyond those of the individual materials and also opens the door to a wide range of possible applications. In this regard, attempts have been made to integrate 1-D ZnO NRs with 2-D graphene to synthesize the novel material structure for investigating its optoelectrical properties and its application in gas sensor devices. In this work, we present a straightforward solution-based method to prepare a gas sensor device from ZnO NRs vertically grown on a chemically converted graphene (CCG) thin film that increases the density of vertically aligned ZnO NRs with preferred orientation along the (002) plane.

2. Experimental

A ZnO-graphene gas sensor was fabricated by a simple solution-based process that consists of two main steps: synthesis of CCG film and direct growth of ZnO NRs on it. The preparation of the CCG film is described in detail elsewhere [3]. To prepare a ZnO seed layer, the CCG film was wetted with an ethanolic solution of 5 mM zinc acetate dehydrate (98%, Aldrich), rinsed with ethanol after 10 s, and dried by blowing with a stream of argon. This coating step was repeated five times. The CCG film coated with a thin layer of zinc acetate crystallites was heated to 350 °C in air for 30 min to form the ZnO seed layer. Finally, the ZnO NRs were directly grown by placing the substrate on a stainless steel holder in a 100 mL aqueous solution of 16 mM zinc nitrate hexahydrate and 25 mM methanamine, and heating the solution at 90 °C in an oven for 4 h. The substrates covered with the ZnO NRs were rinsed with water and dried in an argon stream. The surface morphology, crystal phase and crystalllinity of the samples were investigated by scanning electron microscopy (SEM), atomic force microscopy (AFM), Raman spectroscopy (Witec alpha 300SR) and high resolution X-ray diffraction (HRXRD, Bruker D8 Advance), respectively.

The ZnO NRs-CCG sensor was inserted on a panel and then placed in a sealed chamber with heating facility. N_2 and O_2 were used as carrier gases and H_2S as a test gas. Prior to H_2S detection, the sensor was soaked in N_2 or O_2 until the sensor resistance reached a stationary value. The gas flow rate was controlled with a mass flow controller. The change of the sensor resistance due to H_2S adsorption was

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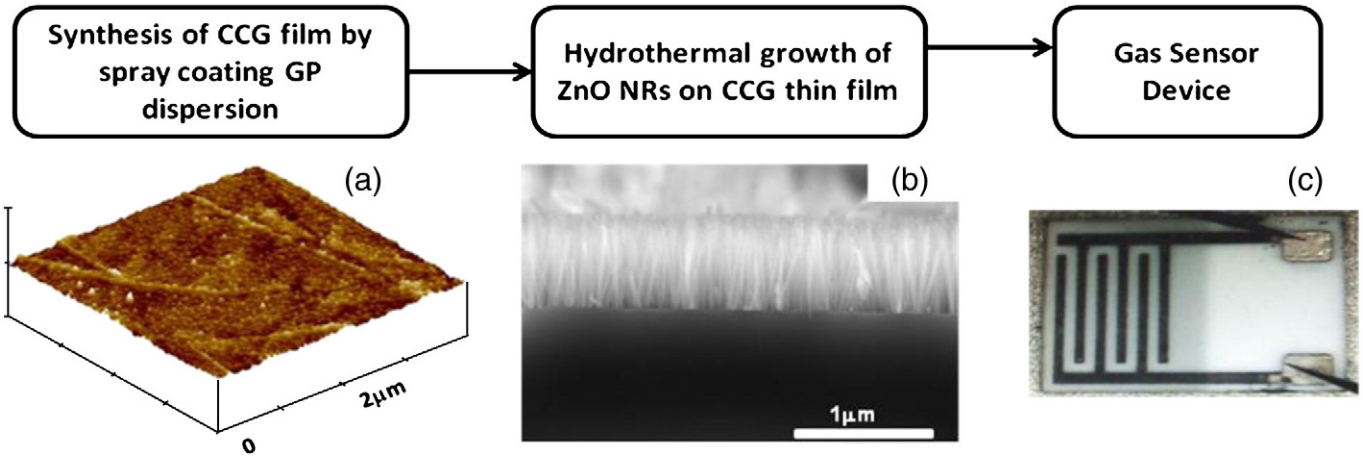

Fig. 1. (a) 3-dimensional AFM surface morphology of the CCG thin film with dots, (b) SEM image of ZnO NRs directly grown on the CCG film, and (c) gas sensor device.

monitored, analyzed and stored by a computer with DAQ (data acquisition board) and Lab-VIEW software.

3. Results and discussion

Fig. 1 depicts the fabrication process of a ZnO NRs-CCG gas sensor that consists of two main steps: synthesis of CCG film and direct growth of ZnO NRs on this film. The surface morphology of the produced CCG film with small white dots which were formed during spray-coating of graphene oxide (GO)-hydrazine dispersion at a low temperature was clearly observed in Fig. 1(a). At a low temperature, the reduction rate is slow and thus the GO sheets are reduced after deposition onto the substrate. Consequently the by-products of reduction, such as H_2O, NO_2, and N_2 are trapped in the CCG sheets, resulting in the formation of small white dots. The cross-sectional SEM image of the ZnO NRs grown on the CCG film is exhibited in Fig. 1 (b). The ZnO NRs were found to be vertically grown on the CCG film and the ZnO NRs had typically a length of 0.5–2 μm with a diameter of around 100 nm. Fig. 1(c) shows a ceramic plate of the ZnO NRs-CCG sensor employed in our study. Pt alloy electrodes were coated with an interdigit structure on one side and heater patterns of RuO_2 were pasted on the other side by a screen printing method.

To explore the effect of dot on the nanorod growth, ZnO NRs were grown on the CCG film with and without dots under identical growth condition. The dot may form a step edge in the CCG layer. The nucleation and growth of the ZnO are more favourable along the step edge [4]. In addition, the dots may serve as nucleation centers for nanorod growth. Consequently, ZnO NRs grown on the CCG layer with dots (Fig. 2(a)) had a larger diameter size compared to those grown on the CCG layer without dots (Fig. 2(b)). In Fig. 2(c), the HRXRD spectra of ZnO NRs on the CCG layer with dots possessed a sole strong peak of the (002) plane implying that the ZnO NRs were grown along the c-axis. On the other hand, several peaks were observed for ZnO NRs grown on the CCG layer without dots (Fig. 2(d)). The HRXRD results are well consistent with the SEM images.

Fig. 3(a) exhibits the PL spectra of the sample. Generally, a UV emission peak centered around 380 nm corresponds to the near band edge emission and a yellow emission broadband is related to the

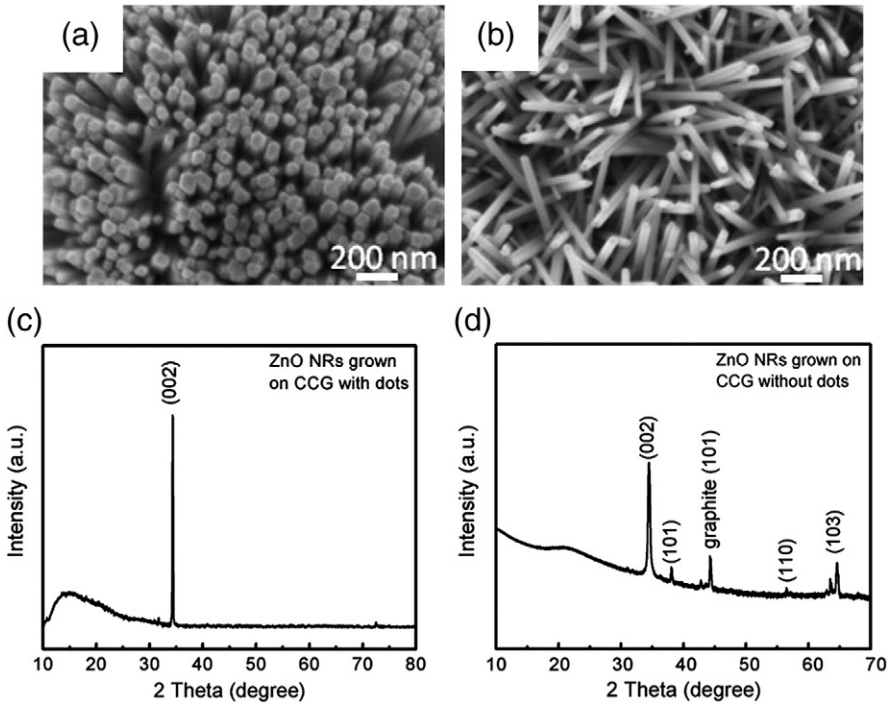

Fig. 2. SEM images and HRXRD spectra of ZnO NRs on (a, c) the CCG film with dots and (b, d) without dots.

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